Features
- Fundamental Image Reject Mixer
- 8.0 dB Conversion Loss
- 20.0 dB Image Rejection
- +25.0 dBm Input Third Order Intercept (IIP3)
- 100% On-Wafer RF Testing
- 100% Visual Inspection to MIL-STD-883 Method 2010
- RoHS* Compliant and 260°C Reflow Compatible

Description
M/A-COM Tech’s 12.0-40.0 GHz GaAs MMIC fundamental image reject mixer can be used as an up- or down-converter. The device has a conversion loss of 8.0 dB with a 20.0 dB image rejection across the band. I and Q mixer outputs are provided and an external 90 degree hybrid is required to select the desired sideband. This MMIC uses M/A-COM Tech’s GaAs PHEMT device model technology, and is based upon electron beam lithography to ensure high repeatability and uniformity. The chip has surface passivation to protect and provide a rugged part with backside via holes and gold metallization to allow either a conductive epoxy or eutectic solder die attach process. This device is well suited for Millimeter-wave Point-to-Point Radio, LMDS, SATCOM and VSAT applications.

Ordering Information

<table>
<thead>
<tr>
<th>Part Number</th>
<th>Package</th>
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<tbody>
<tr>
<td>XM1001-BD-000V</td>
<td>“V” - vacuum release gel paks</td>
</tr>
<tr>
<td>XM1001-BD-EV1</td>
<td>evaluation module</td>
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</table>

Absolute Maximum Ratings

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Absolute Max.</th>
</tr>
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<tbody>
<tr>
<td>Gate Bias Voltage (Vg)</td>
<td>+0.3 VDC</td>
</tr>
<tr>
<td>Input Power (RF Pin)</td>
<td>+20.0 dBm</td>
</tr>
<tr>
<td>Input Power (IF Pin)</td>
<td>+20.0 dBm</td>
</tr>
<tr>
<td>Storage Temperature (Tstg)</td>
<td>-65 °C to +165 °C</td>
</tr>
<tr>
<td>Operating Temperature (Ta)</td>
<td>-55 °C to +125 °C</td>
</tr>
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</table>
## XM1001-BD

**Image Reject Mixer**  
12.0-40.0 GHz

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Units</th>
<th>Min.</th>
<th>Typ.</th>
<th>Max.</th>
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</thead>
<tbody>
<tr>
<td>Frequency Range (RF) Lower Side Band</td>
<td>GHz</td>
<td>12.0</td>
<td>-</td>
<td>38.0</td>
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<tr>
<td>Frequency Range (LO)</td>
<td>GHz</td>
<td>8.0</td>
<td>-</td>
<td>42.0</td>
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<tr>
<td>Frequency Range (IF)</td>
<td>GHz</td>
<td>DC</td>
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<td>4.0</td>
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<tr>
<td>RF Return Loss (S11)</td>
<td>dB</td>
<td>-</td>
<td>10.0</td>
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<tr>
<td>IF Return Loss (S22)</td>
<td>dB</td>
<td>-</td>
<td>TBD</td>
<td>-</td>
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<tr>
<td>LO Return Loss (S33)</td>
<td>dB</td>
<td>-</td>
<td>TBD</td>
<td>-</td>
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<tr>
<td>Conversion Loss (S21)</td>
<td>dB</td>
<td>-</td>
<td>8.0</td>
<td>-</td>
</tr>
<tr>
<td>LO Input Drive (P LO)</td>
<td>dBm</td>
<td>-</td>
<td>+12.0</td>
<td>-</td>
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<tr>
<td>Image Rejection</td>
<td>dBC</td>
<td>-</td>
<td>20.0</td>
<td>-</td>
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<tr>
<td>Isolation LO/RF</td>
<td>dB</td>
<td>-</td>
<td>16.0</td>
<td>-</td>
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<tr>
<td>Isolation LO/IF</td>
<td>dB</td>
<td>-</td>
<td>TBD</td>
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</tr>
<tr>
<td>Isolation RF/IF</td>
<td>dB</td>
<td>-</td>
<td>TBD</td>
<td>-</td>
</tr>
<tr>
<td>Input Third Order Intercept (IIP3)</td>
<td>dBm</td>
<td>-</td>
<td>+25.0</td>
<td>-</td>
</tr>
<tr>
<td>Gate Bias Voltage (Vg1)</td>
<td>VDC</td>
<td>-2.0</td>
<td>-0.5</td>
<td>+0.1</td>
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</tbody>
</table>

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XM1001-BD

Image Reject Mixer
12.0-40.0 GHz

Rev. V1

Typical Performance Curves

XM1001-BD Vg=0.5 VDC, USB
LO=+12.0 dBm, IF=2.0 GHz, RF=20.0 dBm, ~4840 Devices

XM1001-BD Vg=0.5 VDC, LSB
LO=+12.0 dBm, IF=2.0 GHz, RF=20.0 dBm, ~4840 Devices

XM1001-BD Vg=0.5 VDC, USB
LO=+12.0 dBm, IF=2.0 GHz, RF=20.0 dBm, ~4840 Devices

XM1001-BD Vg=0.5 VDC, LSB
LO=+12.0 dBm, IF=2.0 GHz, RF=20.0 dBm, ~4840 Devices

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Image Reject (dBc)
Max Median Mean -3sigma

Conversion Loss (dB)
Max Median Mean -3sigma

RF Frequency (GHz)
Typical Performance Curves (cont.)

XM1001-BD Vg=0.5 VDC, USB
LO=+12.0 dBm, IF=2.0 GHz, RF=20.0 dBm, ~140 Devices

XM1001-BD Vg=0.5 VDC, LSB
LO=+12.0 dBm, IF=2.0 GHz, RF=20.0 dBm, ~140 Devices

XM1001-BD Vg=0.5 VDC, USB/LSB
LO=+12.0 dBm, IF=2.0 GHz, RF=20.0 dBm, ~130 Devices
Typical Performance Curves (cont.)

(Vg=0.5V, PRF=-10dBm IF=2GHz): USB PLO=+12dBm
Image Rejection (dBc) & Conversion Gain (dB) vs. LO freq (GHz) & RF freq (GHz)

(USB, Vg=0.5V, PRF=-10dBm, IF=2GHz): 1 device and different powers
Image Rejection (dBc) & Conversion Gain (dB) vs. LO freq (GHz) & RF freq (GHz)

USB Conversion Gain/Image Rejection vs Frequency and for different Vg bias (-2.1V to 0.1V with 0.2V steps) PLO=+12dBm

(LSB, Vg=0.5V, PRF=-10dBm, IF=2GHz): 1 device and different powers
Image Rejection (dBc) & Conversion Gain (dB) vs. LO freq (GHz) & RF freq (GHz)

LSB Conversion Gain vs Frequency and for different Vg bias (-2.1V to 0.1V with 0.2V steps) PLO=+12dBm
Typical Performance Curves (cont.)
XM1001-BD

Image Reject Mixer
12.0-40.0 GHz

Typical Performance Curves (cont.)
Image Reject Mixer
12.0-40.0 GHz

Mechanical Drawing

(Note: Engineering designator is 20IRF0374)
Units: millimeters (inches) Bond pad dimensions are shown to center of bond pad.
Thickness: 0.110 +/- 0.010 (0.0043 +/- 0.0004), Backside is ground, Bond Pad/Backside Metallization: Gold
All Bond Pads are 0.100 x 0.100 (0.004 x 0.004).
Bond pad centers are approximately 0.109 (0.004) from the edge of the chip.
Dicing tolerance: +/- 0.005 (+/- 0.0002). Approximate weight: 1.592 mg.
Bond Pad #1 (RF) Bond Pad #3 (Vg) Bond Pad #5 (IF2)
Bond Pad #2 (IF1) Bond Pad #4 (LO)

Bias Arrangement

Bypass Capacitors - See App Note [2]
**App Note [1] Biasing** - As shown in the bonding diagram, the pHEMT mixer devices are operated using a separate gate voltage $V_{g1}$. Set $V_{g1}=-0.5V$ for optimum conversion loss performance.

**App Note [2] Bias Arrangement** - Each DC pad ($V_{g1}$) needs to have DC bypass capacitance (~100-200 pF) as close to the device as possible. Additional DC bypass capacitance (~0.01 uF) is also recommended.

**App Note [3] USB/LSB Selection** -

For Upper Side Band Operation (USB): With IF1 and IF2 connected to the direct port (0°) and coupled port (90°) respectively as shown in the diagram, the USB signal will reside on the isolated port. The input port must be loaded with 50 ohms.

For Lower Side Band Operation (LSB): With IF1 and IF2 connected to the direct port (0°) and coupled port (90°) respectively as shown in the diagram, the LSB signal will reside on the input port. The isolated port must be loaded with 50 ohms.

**Note:** The coupled port can be used as an alternative input but the port location of the Coupled and Direct ports reverse.

An alternate method of Selection of USB or LSB:
Handling Procedures
Please observe the following precautions to avoid damage:

Static Sensitivity
Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these class 2 devices.
XM1001-BD

Image Reject Mixer
12.0-40.0 GHz

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